



ONS00504
FILE

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Date : 4/7/2005
IN RE APPLICATION OF: Stephen P. Robb
APPLN. NO. : 10/678769
FILED : 10/6/2003
FOR : POWER SWITCH STRUCTURE WITH LOW
RDSON AND LOW CURRENT LIMIT AND METHOD
EXAMINER : Ngan Ngo
Phone : 571-272-1711
Group : 2832

DISCLOSURE STATEMENT UNDER 37 C.F.R. 1.97

Honorable Assistant Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

SIR:

Please consider this Information Disclosure Statement in the above application. Applicant's undersigned representative hereby certifies that each item of information contained in the attached Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of this statement. A copy of the listed prior art is enclosed herewith.

A copy of the International Search Report received in the counterpart application is also enclosed.

No representation is made or intended that a search has been made or that no better prior art than that listed is available.

Respectfully submitted,
Stephen P. Robb, et al.

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FORM PTO-1449	U.S. DEPARTMENT OF COMMERCE	ATTY. DOCKET NO. ONS00504	SERIAL NO. 10/678769
PATENT AND TRADEMARK OFFICE		APPLICANT Stephen P. Robb et al.	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use several sheets if necessary)</i>		FILING DATE 10/6/2003	GROUP 2832



U.S. PATENT DOCUMENTS

EXAMINE R INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
	5101313	3/31/1992	Tighe et al.	361	10	
	6400203	6/4/2002	Rezzi et al.	327	309	
	US2003/0169 025	9/11/2003	Finney	323	276	

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
	WO02/67279A	8/29/2002	WIPO	H01H	3/26	YES
						NO

OTHER DOCUMENTS (Including Author, Title, Date Pertinent Pages, Etc.)

Gediga S. et al., "High Power IGBT Converters with New Gate Drive and Protection Circuit", EPE '95: 6th. European Conference on Power Electronics and Applications, Brussels, EPE Association, Vol. 1 Conf. 6, 19 September 1995, pages 1066-1070, XP000537497

EXAMINER

**DATE
CONSIDERED**

EXAMINER: Initial citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.